













SN74AUP1G14

SCES578J - JUNE 2003 - REVISED SEPTEMBER 2017

# SN74AUP1G14 Low-Power Single Schmitt-Trigger Inverter

#### **Features**

- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Low Static-Power Consumption  $(I_{CC} = 0.9 \mu A Maximum)$
- Low Dynamic-Power Consumption  $(C_{pd} = 4.4 \text{ pF Typical at } 3.3 \text{ V})$
- Low Input Capacitance (C<sub>I</sub> = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V<sub>CC</sub>
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Includes Schmitt-Trigger Inputs
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $t_{pd} = 4.9 \text{ ns Maximum at } 3.3 \text{ V}$

## **Applications**

- **AV Receivers**
- **Smartphones**
- Blu-ray Players and Home Theaters
- **DVD Recorders and Players**
- Desktop or Notebook PCs
- **Embedded PCs**
- **GPS: Personal Navigation Devices**
- Mobile Internet Devices
- Portable Media Players
- **Smoke Detectors**
- Solid State Drive (SSD): Enterprise
- High-Definition (HDTV)
- Tablets: Enterprise
- Audio Docks: Portable
- DVR and DVS

### 3 Description

The AUP family is TI's premier solution to the industry's low power needs in battery-powered portable applications. This family assures a very low static and dynamic power consumption across the entire V<sub>CC</sub> range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see AUP - The Lowest-Power Family and Excellent Signal Integrity).

This device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74AUP1G14DBV	SOT-23 (5)	2.90 mm x 1.60 mm
SN74AUP1G14DCK	SC70 (5)	2.00 mm x 1.25 mm
SN74AUP1G14DRL	SOT (5)	1.60 mm x 1.20 mm
SN74AUP1G14DRY	SON (6)	1.45 mm x 1.00 mm
SN74AUP1G14DSF	SON (6)	1.00 mm x 1.00 mm
SN74AUP1G14DPW	X2SON (5)	0.80 mm x 0.80 mm
SN74AUP1G14YFP	DSBGA (4)	0.76 mm x 0.76 mm

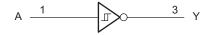
(1) For all available packages, see the orderable addendum at the end of the data sheet.

# Logic Diagram (Positive Logic) (DBV, DCK, DRL, DRY, DSF, DPW, and YZP Packages)



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#### **Logic Diagram (Positive Logic)** (YFP Package)



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

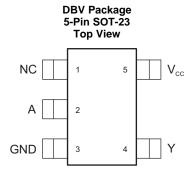
<ul> <li>Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Thermal Information table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Sup Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.</li> <li>Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information section at the end of data sheet</li> <li>Changed formatting of YFP package pinout drawing</li> </ul>	Cł	hanges from Revision I (May 2010) to Revision J	Page
table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Sup Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.  Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information section at the end of data sheet  Changed formatting of YFP package pinout drawing  Deleted YZP package from data sheet	•	Added DPW (X2SON) package	1
<ul> <li>data sheet</li></ul>	•	table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Suppl	•
Deleted YZP package from data sheet	•	Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information section at the end of the data sheet	
	•	Changed formatting of YFP package pinout drawing	3
Added Junction temperature, T <sub>J</sub> in <i>Absolute Maximum Ratings</i>	•	Deleted YZP package from data sheet	3
	•	Added Junction temperature, T <sub>J</sub> in <i>Absolute Maximum Ratings</i>	4

Product Folder Links: SN74AUP1G14

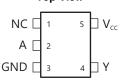
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## 5 Pin Configuration and Functions

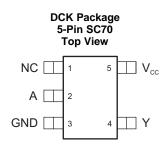


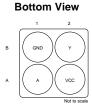




**DRL Package** 



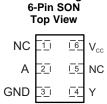




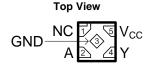
YFP Package

4-Pin DSBGA

N.C. - No internal connection. See mechancial drawings for dimensions.



**DSF Package** 



**DPW Package** 5-Pin X2SON

#### **Pin Functions**

		PIN				
NAME	DBV, DCK, DRL, DPW	DRY, DSF	YFP	I/O	DESCRIPTION	
Α	2	2	A1	1	Logic Input	
GND	3	3	B1	_	Ground	
N.C.	1	1, 5	_	_	No internal connection	
V <sub>CC</sub>	5	6	A2	_	Positive Supply	
Υ	4	4	B2	0	Output	



### 6 Specifications

#### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	4.6	V
VI	Input voltage <sup>(2)</sup>	-		4.6	V
Vo	Voltage range applied to any output in the h	igh-impedance or power-off state (2)	-0.5	4.6	V
Vo	Voltage range applied to any output in the h	igh or low state <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
	Floatusetetis disaberras	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

See(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		0.8	3.6	V
$V_{I}$	Input voltage		0	3.6	٧
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.8 V		-20	μA
		V <sub>CC</sub> = 1.1 V		-1.1	
	High-level output current	V <sub>CC</sub> = 1.4 V		-1.7	
I <sub>OH</sub>		V <sub>CC</sub> = 1.65 V		-1.9	mA
		V <sub>CC</sub> = 2.3 V		-3.1	
		V <sub>CC</sub> = 3 V		-4	
		V <sub>CC</sub> = 0.8 V		20	μA
		V <sub>CC</sub> = 1.1 V		1.1	
	Lave lavel and and annual	V <sub>CC</sub> = 1.4 V		1.7	
l <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9	mA
		V <sub>CC</sub> = 2.3 V		3.1	
		V <sub>CC</sub> = 3 V		4	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to assure proper device operation. See Implications of Slow or Floating CMOS Inputs.

<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### 6.4 Thermal Information

					SN74AUP1G1	4			
	THERMAL METRIC <sup>(1)</sup>		DSF (SON)	YFP (DSBGA)	DPW (X2SON)	DBV (SOT-23)	DCK (SC70)	DRL (SOT)	UNIT
		6 PINS	6 PINS	4 PINS	5 PINS	5 PINS	5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	347.8	386.2	179.3	489.2	289.1	325.1	324.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	237.7	192.9	2.8	226.3	213.7	229.1	156.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	210.6	242.2	58.3	352.9	123.0	123.2	172.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	64.4	28.9	1.1	38.2	104.5	96.3	21.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	210.6	241.9	58.6	352.1	122.3	122.4	173.6	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	150.8	N/A	N/A	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

### 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP	MAX	UNIT
		T <sub>A</sub> = 25°C	0.01/	0.2	0.0	
		$T_A = -40$ °C to +85°C	0.8 V	0.3	0.6	
		T <sub>A</sub> = 25°C	4.4.1/	0.50	0.0	
		$T_A = -40$ °C to +85°C	1.1 V	0.53	0.9	
$V_{T+} = \begin{array}{c} T_A = 25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = -25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = -25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = 25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = -25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = 25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = 25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = 25^{\circ}C \\ T_A = -40^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = -25^{\circ}C \ \text{to} + 85^{\circ}C \\ T_A = -25^{\circ}C \\ T_$	0.74	4.44				
.,	Positive-going input	$T_A = -40$ °C to +85°C	1.4 V	0.74	1.11	V
V <sub>T+</sub>	threshold voltage	T <sub>A</sub> = 25°C	4.05.1/	0.04	4.00	V
		$T_A = -40$ °C to +85°C	1.05 V	0.91	1.29	
		T <sub>A</sub> = 25°C	0.01/	4.07	4 77	
		$T_A = -40$ °C to +85°C	2.3 V	1.37	1.77	
V <sub>T+</sub>		T <sub>A</sub> = 25°C	2.1/	4.00	2.29	
		$T_A = -40$ °C to +85°C	3 V	1.00	2.29	
		T <sub>A</sub> = 25°C	0.8.1/	0.1	0.6	
		$T_A = -40$ °C to +85°C	0.8 V	0.1	0.6	
		T <sub>A</sub> = 25°C	4.4.1/	0.26	0.65	
		$T_A = -40$ °C to +85°C	1.1 V	0.26	0.65	
		T <sub>A</sub> = 25°C	4.4.1/	0.20	0.75	
V	Negative-going input	$T_A = -40$ °C to +85°C	1.4 V	0.39	0.75	V
v <sub>T</sub> _	threshold voltage	T <sub>A</sub> = 25°C	1 CF \/	0.47	0.84	V
		$T_A = -40$ °C to +85°C	1.00 V	0.47	0.64	
		T <sub>A</sub> = 25°C	221/	0.00	1.04	
		$T_A = -40$ °C to +85°C	2.3 V	0.69	1.04	
		T <sub>A</sub> = 25°C	2.1/	0.00	1.04	
		$T_A = -40$ °C to +85°C	3 V	0.88	1.24	



## **Electrical Characteristics (continued)**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TES	T CONDITIONS	V <sub>cc</sub>	MIN	TYP MAX	UNIT
		T <sub>A</sub> = 25°C		0.8.1/	0.07	0.5	
$T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = 25^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $I_{OH} = -20  \mu A$ $I_{OH} = -1.1 \text{ mA}$ $I_{OH} = -1.1 \text{ mA}$ $I_{OH} = -1.9 \text{ mA}$ $I_{OH} = -2.3 \text{ mA}$ $I_{OH} = -3.1 \text{ mA}$ $I_{OH} = -2.7 \text{ mA}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -4 \text{ mA}$ $I_{OL} = 20  \mu A$ $I_{OL} = 1.1 \text{ mA}$		0.8 V	0.07	0.5			
		T <sub>A</sub> = 25°C		4.4.1/	0.00	0.40	
		$T_A = -40$ °C to +85°C		1.1 V	0.08	0.46	
		T <sub>A</sub> = 25°C		4.41/	0.40	0.50	•
	Hysteresis	$T_A = -40$ °C to +85°C		1.4 V	0.18	0.56	.,
$\Delta V_{T}$		T <sub>A</sub> = 25°C					V
		$T_A = -40$ °C to +85°C		1.65 V	0.27	0.66	
							:
		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		2.3 V	0.53	0.92	
		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		3 V	0.79	1.31	
			T <sub>A</sub> = 25°C				
		$I_{OH} = -20 \mu A$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	0.8 V to 3.6 V	V <sub>CC</sub> - 0.1		
			T <sub>A</sub> = 25°C		0.75 × V <sub>CC</sub>		
		$I_{OH} = -1.1 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.1 V	0.7 × V <sub>CC</sub>		:
			T <sub>A</sub> = 25°C		1.11		
		$I_{OH} = -1.7 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.4 V	1.03		
			T <sub>A</sub> = 25°C		1.32		
		$I_{OH} = -1.9 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.65 V	1.3		
V <sub>OH</sub>		T <sub>A</sub> = 25°C		2.05		V	
		$I_{OH} = -2.3 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		1.97		
			T <sub>A</sub> = 25°C	2.3 V	1.9		
	$I_{OH} = -3.1 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		1.85			
			T <sub>A</sub> = 25°C		2.72		
			$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		2.67		
			T <sub>A</sub> = 25°C	3 V	2.6		
		$I_{OH} = -4 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		2.55		:
			T <sub>A</sub> = 25°C				
		$I_{OL} = 20 \mu A$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	0.8 V to 3.6 V		0.1	
			T <sub>A</sub> = 25°C			0.2	:
		I <sub>OL</sub> = 1.1 mA	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.1 V		0.3 × V <sub>CC</sub>	
			T <sub>A</sub> = 25°C			0.31	
		$I_{OL} = 1.7 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.4 V		0.37	
			T <sub>A</sub> = 25°C			0.31	
		$I_{OL} = 1.9 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	1.65 V		0.35	
$V_{OL}$			T <sub>A</sub> = 25°C			0.31	V
		$I_{OL} = 2.3 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.33	
			T <sub>A</sub> = 25°C	2.3 V		0.44	
		$I_{OL} = 3.1 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.45	
			T <sub>A</sub> = 25°C			0.31	
		$I_{OL} = 2.7 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.33	
			T <sub>A</sub> = 25°C	3 V		0.44	
		$I_{OL} = 4 \text{ mA}$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.45	
			T <sub>A</sub> = 25°C			0.43	
$I_{\parallel}$	A input	$V_I = GND \text{ to } 3.6 \text{ V}$	$T_A = 23 \text{ C}$ $T_A = -40 \text{ °C to } +85 \text{ °C}$	0 V to 3.6 V		0.1	μA
		V	T <sub>A</sub> = 25°C			0.3	
$I_{OFF}$		$V_1$ or $V_0 = 0 \text{ V to } 3.6 \text{ V}$	$T_A = 25 \text{ C}$ $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	0 V		0.2	μΑ
			T <sub>A</sub> = -40 °C to +65 °C				
$\Delta$ l <sub>OFF</sub>		$V_1$ or $V_0 = 0 \text{ V to } 3.6 \text{ V}$	$T_A = 25^{\circ} \text{C}$ $T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$	0 V to 0.2 V		0.2	
		.0 0.000	1A = -40 C 10 +00 C			0.6	

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### **Electrical Characteristics (continued)**

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	V <sub>CC</sub>	MIN	TYP MAX	UNIT
	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V})$	T <sub>A</sub> = 25°C	0.8 V to 3.6 V	8 V to 3 6 V		μA
Icc	I <sub>O</sub> = 0	$T_A = -40$ °C to +85°C	0.6 V to 3.6 V		0.9	μΑ
A1	$V_1 = V_{CC} - 0.6 \text{ V}$ $I_0 = 0$	T <sub>A</sub> = 25°C	3.3 V		40	
Δl <sub>CC</sub>	I <sub>O</sub> = 0	$T_A = -40$ °C to +85°C	3.3 V		50	μA
C	$V_{I} = V_{CC}$ or GND	$T_A = -40$ °C to +85°C	0 V	1.5		pF
C <sub>I</sub>	VI = VCC OI GIVD	$T_A = -40$ °C to +85°C	3.6 V	1.5		þг
Co	V <sub>O</sub> = GND	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	0 V	2.5		pF

## 6.6 Switching Characteristics: $C_L = 5 pF$

over recommended operating free-air temperature range,  $C_L = 5$  pF (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST (	CONDITIONS	MIN	TYP	MAX	UNIT
			V <sub>CC</sub> = 0.8 V	T <sub>A</sub> = 25°C		16.3		
			\/ 42\/.04\/	$T_A = 25^{\circ}C$	4.2	6.9	11.7	
			$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$T_A = -40$ °C to +85°C	0.9		15	
t <sub>pd</sub>			V -15V : 01V	$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$ $T_{A} = -40^{\circ}\text{C to} + 85^{\circ}\text{C}$ $T_{A} = 25^{\circ}\text{C}$	3.7	5.2	8.4	
			V <sub>CC</sub> = 1.3 V ± 0.1 V		1.7		10.7	
	Α	Υ	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$		3.3	4.4	6.9	ns
			VCC = 1.6 V ± 0.15 V	$T_A = -40$ °C to +85°C	1.9		8.5	
			$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = 25^{\circ}C$	2.8	3.5	4.8	
			V <sub>CC</sub> = 2.3 V ± 0.2 V	$T_A = -40$ °C to +85°C	1.8		6.1	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = 25^{\circ}C$	2.5	3	4	
			VCC = 3.3 V ± 0.3 V	$T_A = -40$ °C to +85°C	1.7		4.9	

## 6.7 Switching Characteristics: $C_L = 10 pF$

over recommended operating free-air temperature range, C<sub>L</sub> = 10 pF (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST (	CONDITIONS	MIN	TYP	MAX	UNIT
			V <sub>CC</sub> = 0.8 V	T <sub>A</sub> = 25°C		18.4		
			$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$T_A = 25^{\circ}C$	4.6	7.9	13.4	
				$T_A = -40$ °C to +85°C	1.3		16.7	
		Y	V <sub>CC</sub> = 1.5 V ± 0.1 V	T <sub>A</sub> = 25°C	4	6	9.6	
				$T_A = -40$ °C to +85°C	2.2		11.8	
t <sub>pd</sub>	Α		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	T <sub>A</sub> = 25°C	3.6	5	7.9	
				$T_A = -40$ °C to +85°C	2.4		9.5	
			V 25V 02V	$T_A = 25^{\circ}C$	3.2	4	5.5	
		$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40$ °C to +85°C	2.3		6.8		
			V 00V 00V	T <sub>A</sub> = 25°C	2.9	3.5	4.6	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40$ °C to +85°C	2.1		5.6	



## 6.8 Switching Characteristics: C<sub>L</sub> = 15 pF

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST C	CONDITIONS	MIN	TYP	MAX	UNIT
			V <sub>CC</sub> = 0.8 V	T <sub>A</sub> = 25°C		20.1		
			$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$T_A = 25^{\circ}C$	5.5	8.7	14	
				$T_A = -40$ °C to +85°C	2.5		17.3	
			$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$	$T_A = 25^{\circ}C$	4.7	6.7	10	
		VCC = 1.5 V ± 0.1 V	$T_A = -40$ °C to +85°C	3		12.5		
t <sub>pd</sub>	Α	Y	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	T <sub>A</sub> = 25°C	4.2	5.6	8.3	ns
				$T_A = -40$ °C to +85°C	3		10.1	
			V 25V . 02V	T <sub>A</sub> = 25°C	3.6	4.5	5.9	
			$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.7		7.4	
			.,	T <sub>A</sub> = 25°C	3.3	3.9	5	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40$ °C to +85°C	2.5		6.1	

## 6.9 Switching Characteristics: $C_L = 30 pF$

over recommended operating free-air temperature range, C<sub>L</sub> = 30 pF (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST (	CONDITIONS	MIN	TYP	MAX	UNIT
			V <sub>CC</sub> = 0.8 V	$T_A = 25^{\circ}C$		25.7		
			V <sub>CC</sub> = 1.2 V ± 0.1 V	$T_A = 25^{\circ}C$	7.4	11.2	17.1	
		V <sub>CC</sub> = 1.2 V ± 0.1 V	$T_A = -40$ °C to +85°C	4.5		20.5		
		$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$	$T_A = 25^{\circ}C$	6.1	8.5	12.3		
			VCC = 1.3 V ± 0.1 V	$T_A = -40$ °C to +85°C	4.6		14.7	
t <sub>pd</sub>	Α	Y	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$T_A = 25^{\circ}C$	5.4	7.2	10.3	ns
				$T_A = -40$ °C to +85°C	4.1		12	
			$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = 25^{\circ}C$	4.7	5.7	7.4	
			$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$T_A = -40$ °C to +85°C	3.7		8.8	
			V 00V 00V	$T_A = 25^{\circ}C$	4.2	5	6.2	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40$ °C to +85°C	3.5		7.3	

### 6.10 Operating Characteristics

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
O Bours their stire constitution			0.8 V	4	
		1.2 V ± 0.1 V	4		
	Dower discination conscitones	f 40 MH=	1.5 V ± 0.1 V	4.1	
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V	4.1	pF
			2.5 V ± 0.2 V	4.3	
			3.3 V ± 0.3 V	4.4	



## 6.11 Typical Characteristics

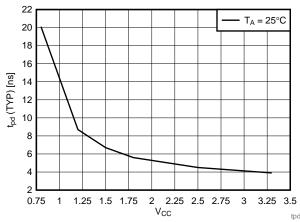


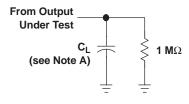
Figure 1. Typical Propagation Delay vs. Supply Voltage ( $C_L = 15 \text{ pF}$ 

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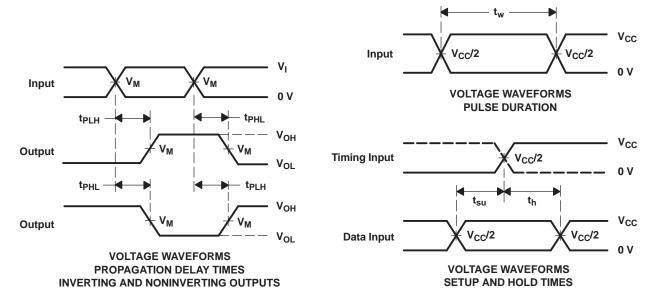
### 7 Parameter Measurement Information

### 7.1 (Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	$V_{CC} = 0.8 \text{ V}$ $V_{CC} = 1.2 \text{ V}$ $\pm 0.1 \text{ V}$		V <sub>CC</sub> = 1.8 V ± 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
C <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>I</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>



NOTES: A.  $C_L$  includes probe and jig capacitance.

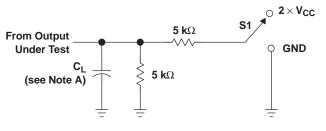
- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f/t_f = 3$  ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- $\begin{array}{ll} \text{D.} & t_{\text{PLH}} \text{ and } t_{\text{PHL}} \text{ are the same as } t_{\text{pd}}. \\ \text{E.} & \text{All parameters and waveforms are not applicable to all devices.} \end{array}$

Figure 2. Load Circuit And Voltage Waveforms

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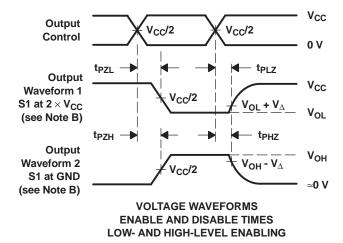
### 7.2 (Enable and Disable Times)



TEST	S1
t <sub>PLZ</sub> /t <sub>PZL</sub>	2×V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	$V_{CC}$ = 1.8 V $\pm$ 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
C <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>I</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>∆</sub>	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r/t_f$  = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit And Voltage Waveforms



### 8 Detailed Description

#### 8.1 Overview

This device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

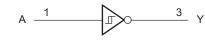
This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

#### 8.2 Functional Block Diagrams



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Figure 4. Logic Diagram (Positive Logic) (DBV, DCK, DRL, DRY, DSF, DPW, and YZP Packages)



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Figure 5. Logic Diagram (Positive Logic) (YFP Package)

### 8.3 Feature Description

### 8.3.1 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the power output of the device to be limited to avoid thermal runaway and damage due to over-current. The electrical and thermal limits defined the in the *Absolute Maximum Ratings* table must be followed at all times.

#### 8.3.2 Schmitt-Trigger Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics* table. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings* table, and the maximum input leakage current, given in the *Electrical Characteristics* table, using ohm's law ( $R = V \div I$ ).

The Schmitt-trigger input architecture provides hysteresis as defined by  $\Delta V_T$  in the *Electrical Characteristics* table, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs slowly will also increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, see *Understanding Schmitt Triggers*.



### **Feature Description (continued)**

#### 8.3.3 Clamp Diodes

The inputs and outputs to this device have negative clamping diodes.

#### **CAUTION**

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

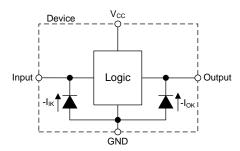


Figure 6. Electrical Placement of Clamping Diodes for Each Input and Output

### 8.3.4 Partial Power Down (Ioff)

The inputs and outputs for this device enter a high impedance state when the supply voltage is 0 V. The maximum leakage into or out of any input or output pin on the device is specified by I<sub>off</sub> in the *Electrical Characteristics* table.

#### 8.3.5 Over-Voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the *Absolute Maximum Ratings* table.

#### 8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74AUP1G14.

**Table 1. Function Table** 

INPUT A	OUTPUT Y
Н	L
L	Н



### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

Mechanical input elements, such as push buttons or rotary knobs, offer simple ways to interact with electronic systems. Typically, these elements have recoil or bouncing, where the mechanical element makes and breaks contact multiple times during human interaction. This bouncing can cause one or more repeated signals to be passed, triggering multiple actions when only a single input was intended. One potential solution to mitigating these multiple inputs is by utilizing a Schmitt-trigger to create a debounce circuit. Figure 7 shows an example of this solution.

#### 9.2 Typical Application

The input due to the push button switches multiple times, causing the output of a non Schmitt-trigger device to trigger multiple times, while the Schmitt-trigger input device with RC delay limits the output pulse to a single pulse desired by the user. The separated positive and negative input voltage threshold values prevent multiple triggers from occurring, see the *Electrical Characteristics* table for  $V_{T+}$ ,  $V_{T-}$ , and  $V_{hys}$  values.

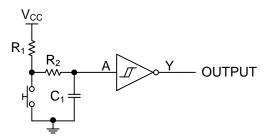


Figure 7. Push Button Debounce Circuit Schematic

#### 9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The drive strength also creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

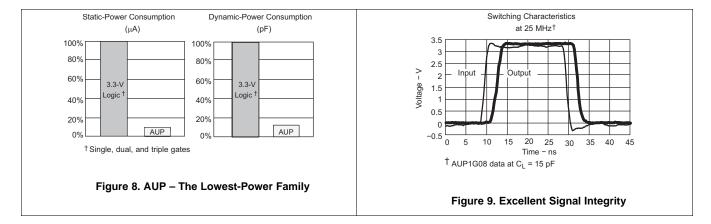
### 9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
  - For specified high and low levels, see (V<sub>T+</sub> and V<sub>T-</sub>) in the Electrical Characteristics table.
  - Inputs are overvoltage tolerant allowing them to go as high as (V<sub>I</sub> max) in the Recommended Operating
     Conditions table at any valid V<sub>CC</sub>.
- 2. Recommended Output Conditions:
  - Load currents should not exceed (I<sub>O</sub> max) per output and should not exceed (Continuous current through V<sub>CC</sub> or GND) total current for the part. These limits are located in the *Absolute Maximum Ratings* table.



## **Typical Application (continued)**

## 9.2.3 Application Curves





### 10 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

### 11 Layout

### 11.1 Layout Guidelines

Even low data rate digital signals can contain high-frequency signal components due to fast edge rates. When a printed-circuit board (PCB) trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 10 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

An example layout is given in Figure 11 for the DPW (X2SON-5) package. This example layout includes a 0402 (metric) capacitor and uses the measurements found in the example board layout appended to this end of this datasheet. A via of diameter 0.1 mm (3.973 mil) is placed directly in the center of the device. This via can be used to trace out the center pin connection through another board layer, or it can be left out of the layout

### 11.2 Layout Example

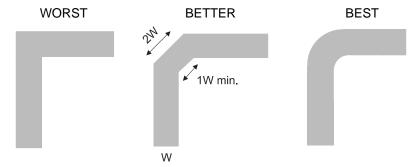


Figure 10. Trace Example

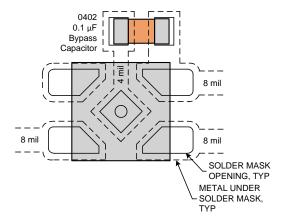


Figure 11. Example Layout With DPW (X2SON-5) Package



### 12 Device and Documentation Support

#### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following: Implications of Slow or Floating CMOS Inputs

### 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7-Oct-2025

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### **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74AUP1G14DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DBVR.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DBVRG4	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DBVRG4.B	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DBVT.B	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R
SN74AUP1G14DCKR	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)
SN74AUP1G14DCKR.B	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)
SN74AUP1G14DCKR1G4	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)
SN74AUP1G14DCKR1G4.B	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)
SN74AUP1G14DCKRG4	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)
SN74AUP1G14DCKT	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFK, HFR)
SN74AUP1G14DCKT.B	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFK, HFR)
SN74AUP1G14DPWR	Active	Production	X2SON (DPW)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(B, BZ)
SN74AUP1G14DPWR.B	Active	Production	X2SON (DPW)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(B, BZ)
SN74AUP1G14DRLR	Active	Production	SOT-5X3 (DRL)   5	4000   LARGE T&R	Yes	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(HF7, HFR)
SN74AUP1G14DRLR.B	Active	Production	SOT-5X3 (DRL)   5	4000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(HF7, HFR)
SN74AUP1G14DRYR	Active	Production	SON (DRY)   6	5000   LARGE T&R	Yes	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DRYR.B	Active	Production	SON (DRY)   6	5000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DRYRG4	Active	Production	SON (DRY)   6	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DRYRG4.B	Active	Production	SON (DRY)   6	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DSFR	Active	Production	SON (DSF)   6	5000   LARGE T&R	Yes	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DSFR.B	Active	Production	SON (DSF)   6	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DSFRG4	Active	Production	SON (DSF)   6	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF
SN74AUP1G14DSFRG4.B	Active	Production	SON (DSF)   6	5000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF

-40 to 85

7-Oct-2025

HF N



SN74AUP1G14YFPR.B

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Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
SN74AUP1G14YFPR	Active	Production	DSBGA (YFP)   4	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-	HF
									N

Yes

**SNAGCU** 

Level-1-260C-UNLIM

3000 | LARGE T&R

Active

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

Production

- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

DSBGA (YFP) | 4

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(1)</sup> Status: For more details on status, see our product life cycle.

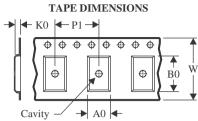
<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.



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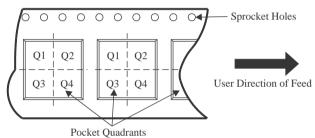
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G14DBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AUP1G14DBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AUP1G14DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74AUP1G14DCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
SN74AUP1G14DCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74AUP1G14DCKR1G4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G14DCKR1G4	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G14DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G14DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G14DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G14DPWR	X2SON	DPW	5	3000	180.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74AUP1G14DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G14DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G14DRYRG4	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G14DSFR	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G14DSFRG4	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2



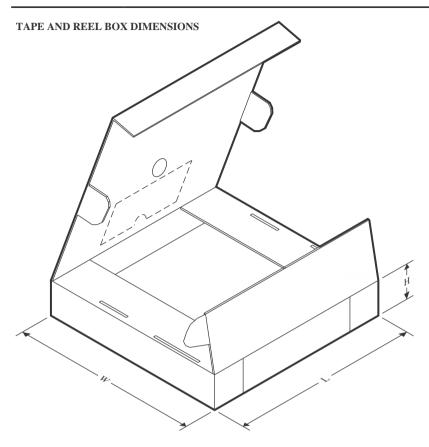
# PACKAGE MATERIALS INFORMATION

www.ti.com 1-Nov-2025

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ı	SN74AUP1G14YFPR	DSBGA	YFP	4	3000	178.0	9.2	0.89	0.89	0.58	4.0	8.0	Q1



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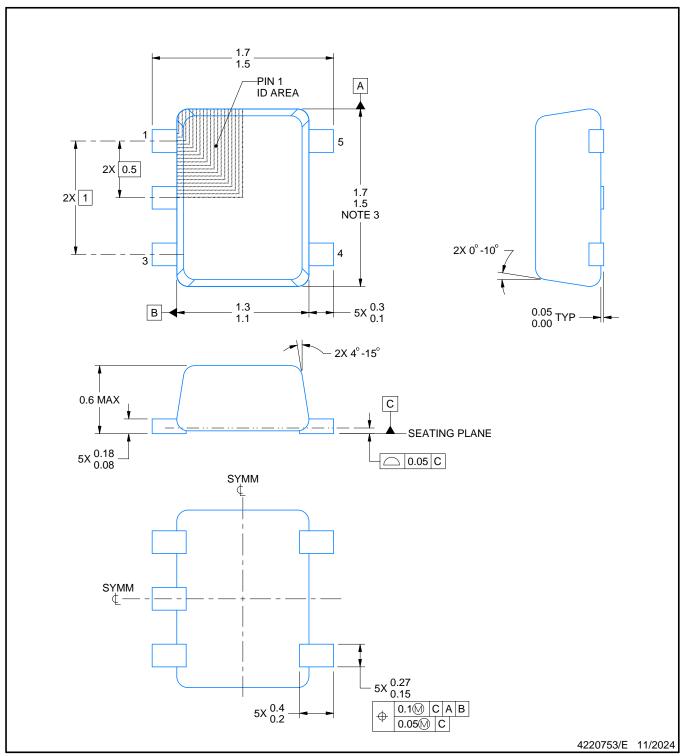


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G14DBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
SN74AUP1G14DBVRG4	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74AUP1G14DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74AUP1G14DCKR	SC70	DCK	5	3000	208.0	191.0	35.0
SN74AUP1G14DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
SN74AUP1G14DCKR1G4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AUP1G14DCKR1G4	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G14DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AUP1G14DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AUP1G14DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G14DPWR	X2SON	DPW	5	3000	210.0	185.0	35.0
SN74AUP1G14DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G14DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G14DRYRG4	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G14DSFR	SON	DSF	6	5000	210.0	185.0	35.0
SN74AUP1G14DSFRG4	SON	DSF	6	5000	210.0	185.0	35.0
SN74AUP1G14YFPR	DSBGA	YFP	4	3000	220.0	220.0	35.0



PLASTIC SMALL OUTLINE

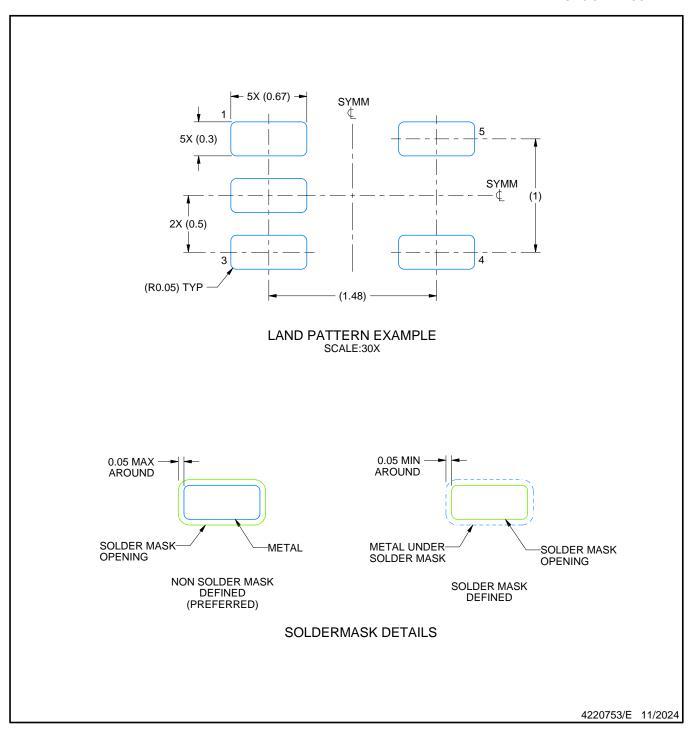


#### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-293 Variation UAAD-1



PLASTIC SMALL OUTLINE

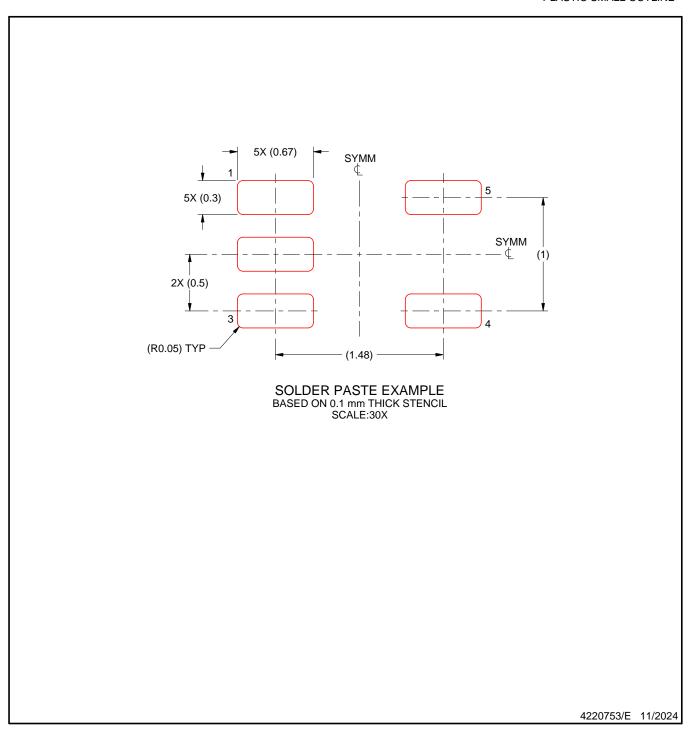


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



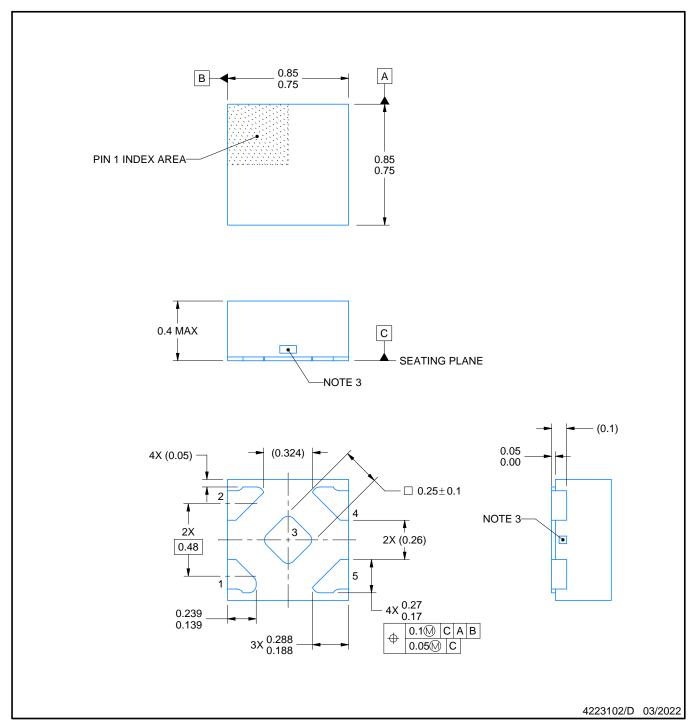


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D





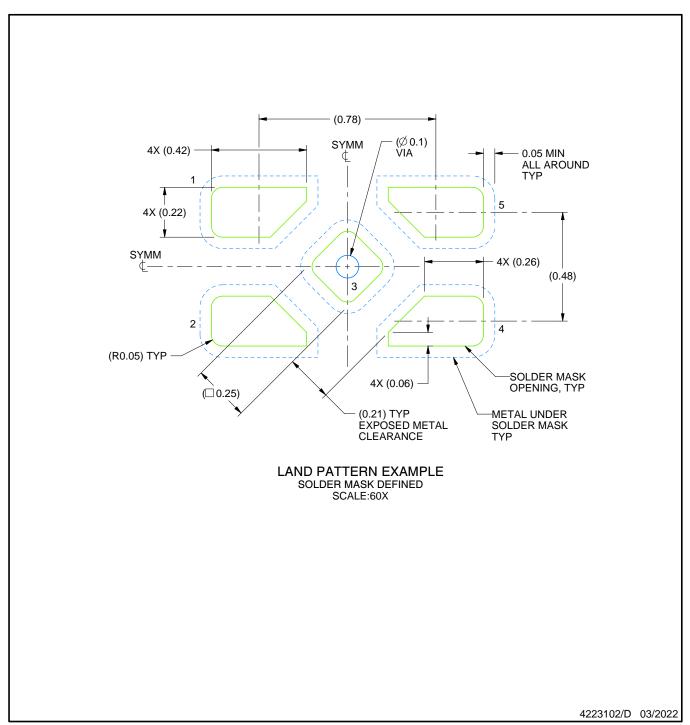


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

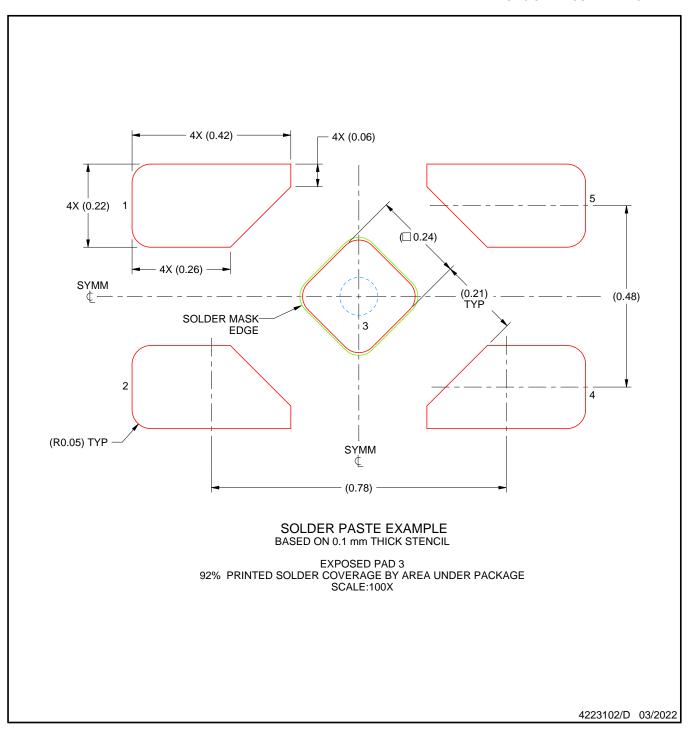




NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





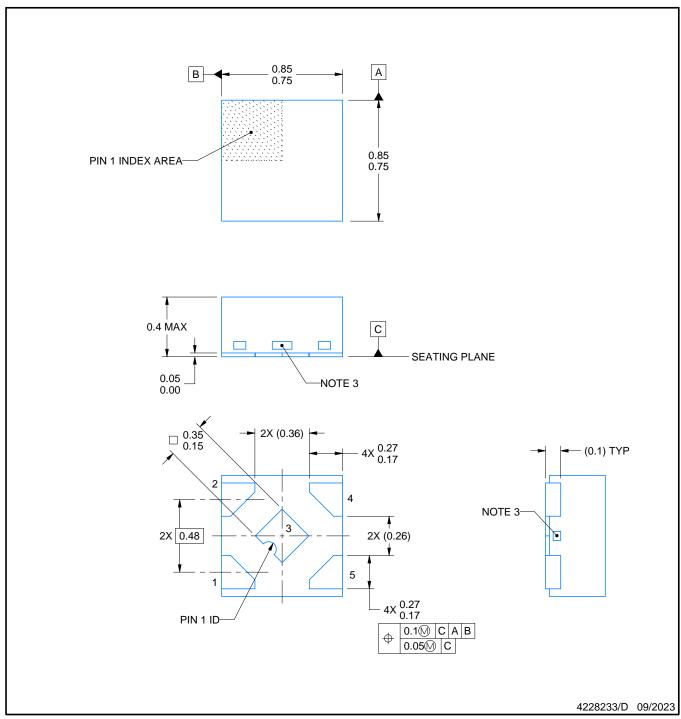
NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



## X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

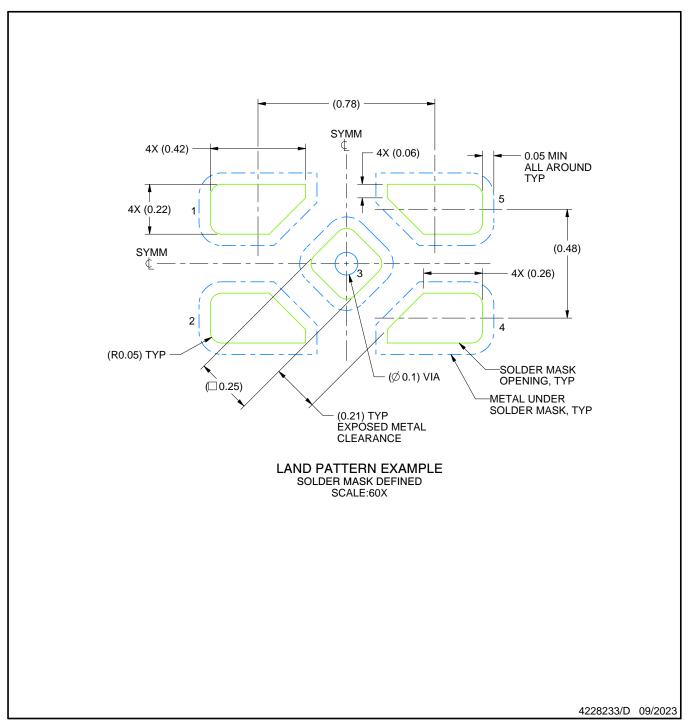


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

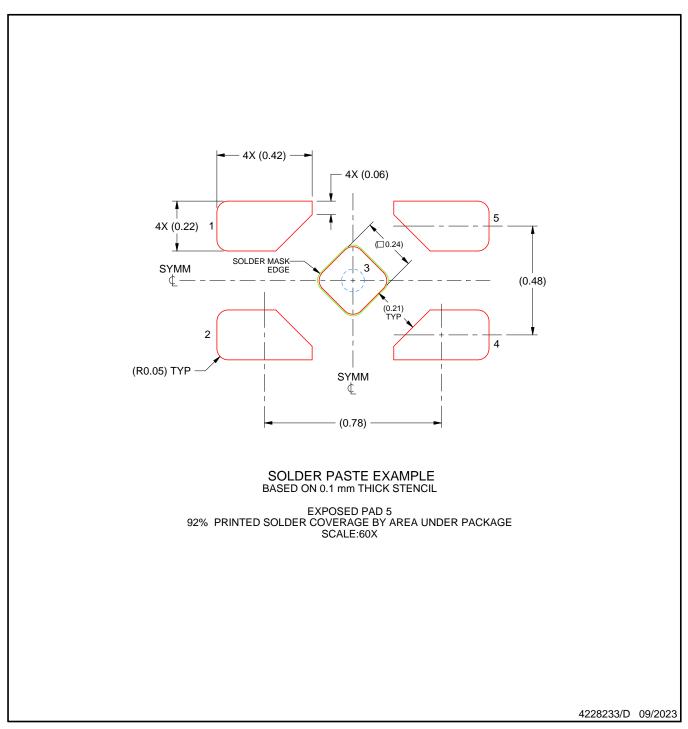




NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).





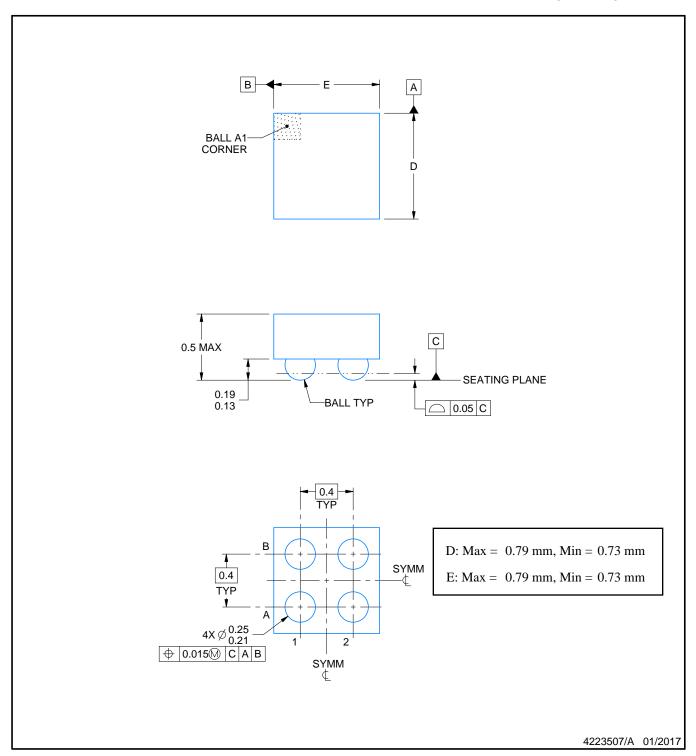
NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY

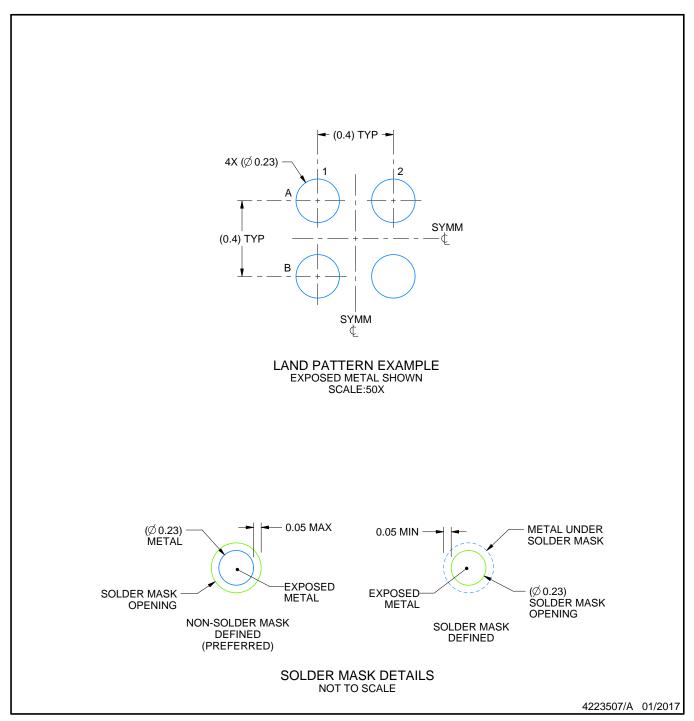


### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

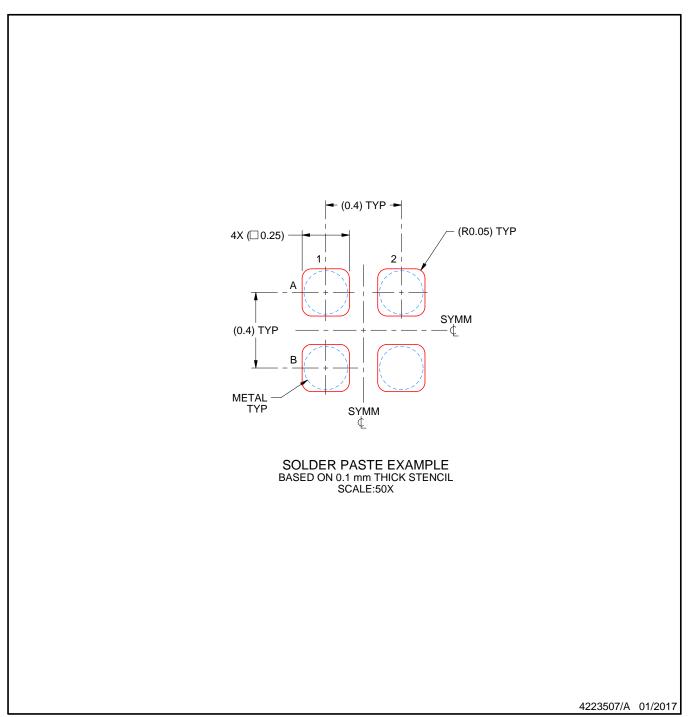


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



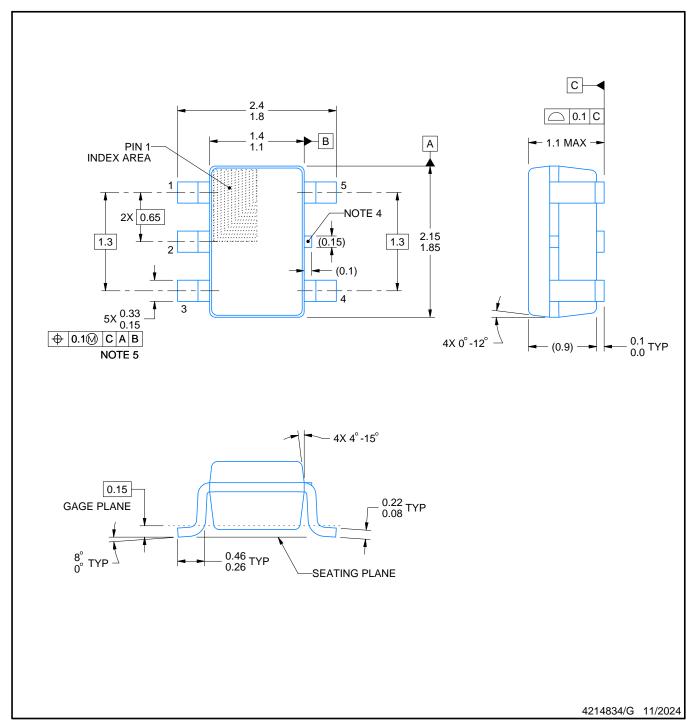
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





SMALL OUTLINE TRANSISTOR

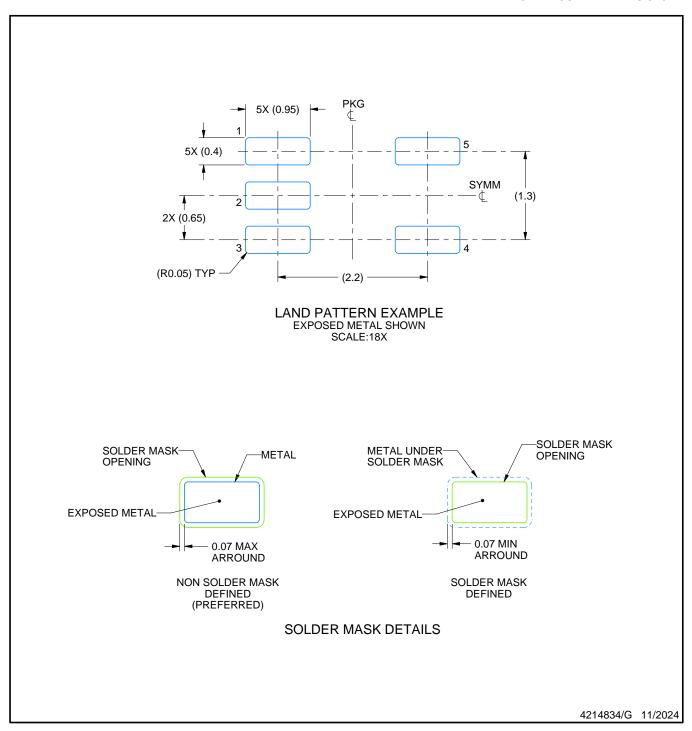


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

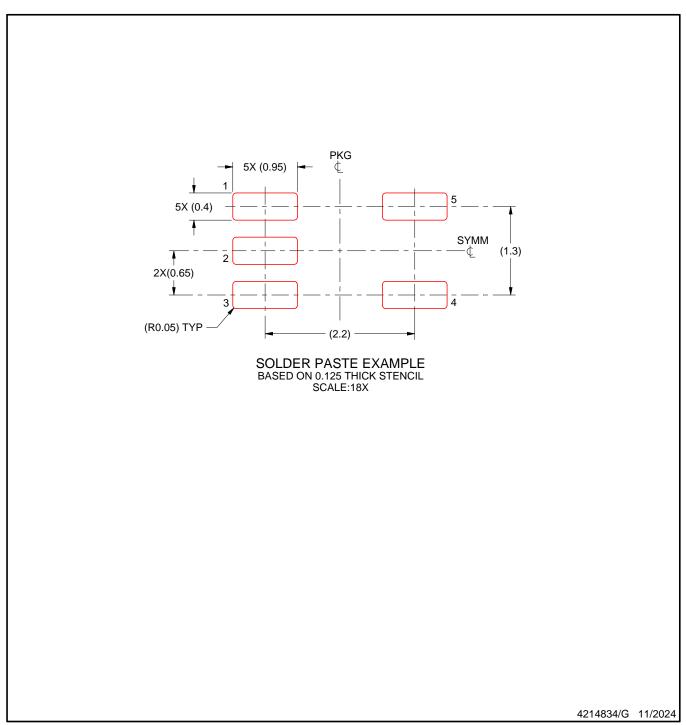




NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



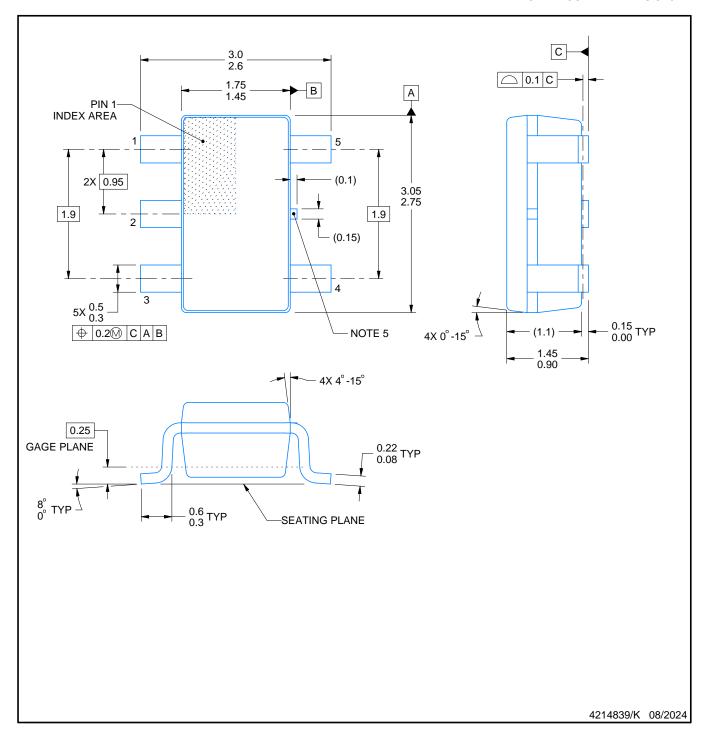


NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.





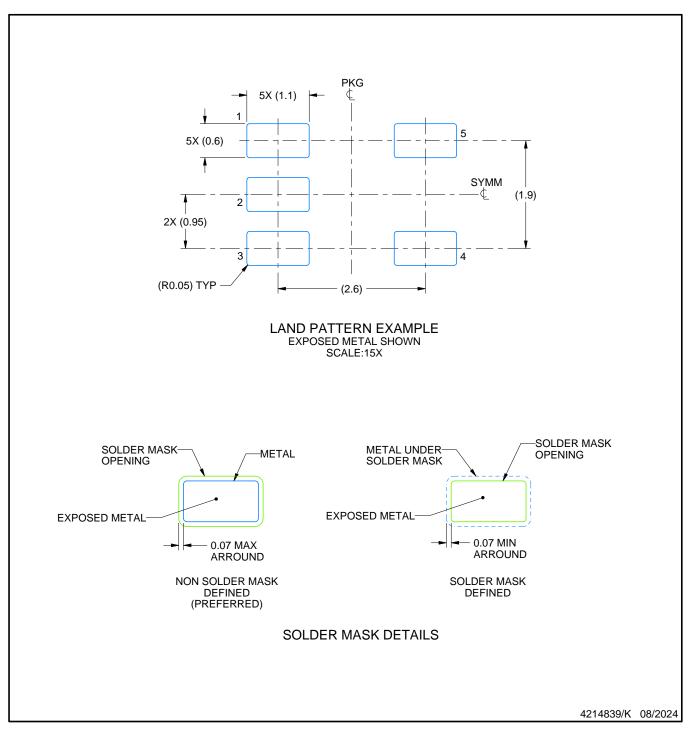


## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



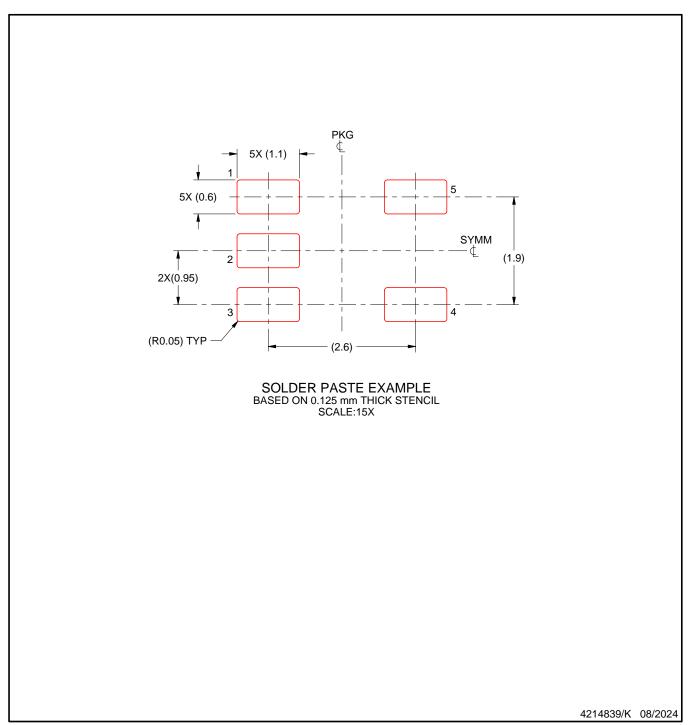


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



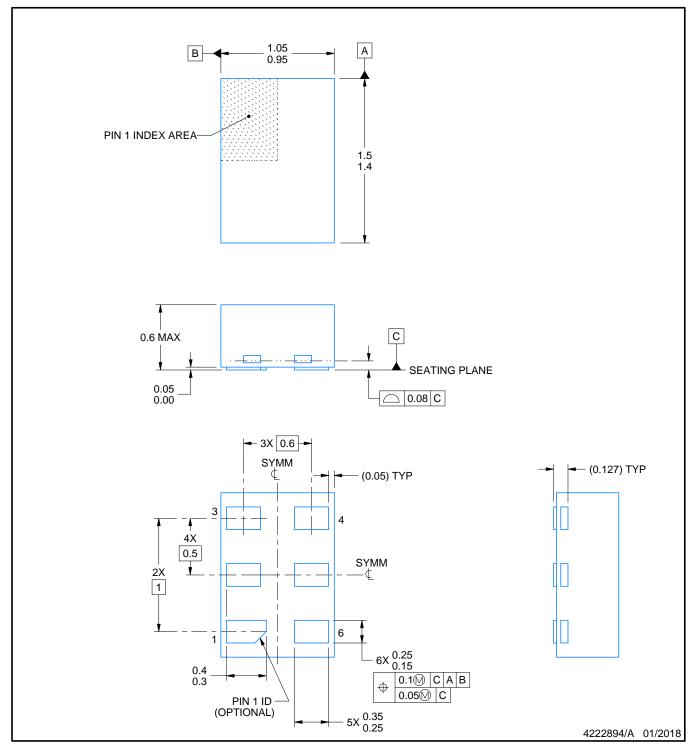


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4207181/G





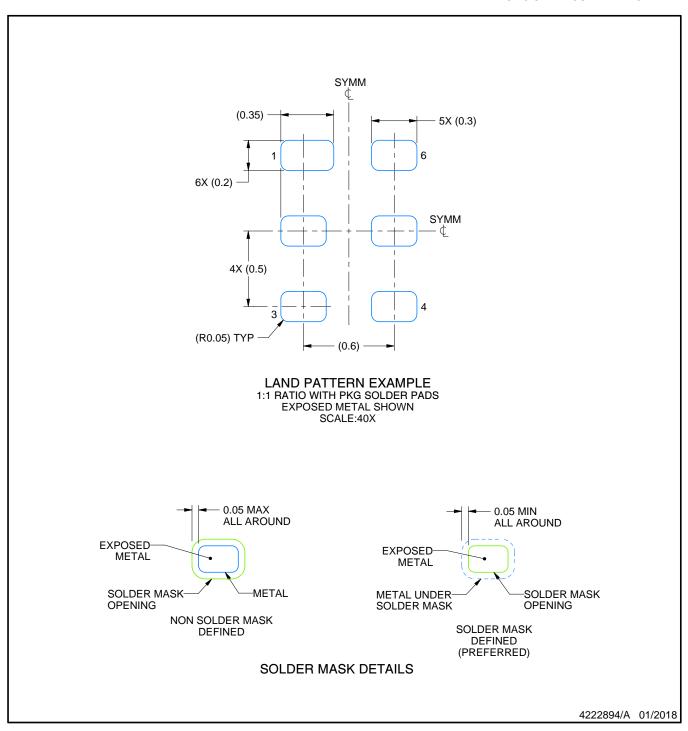


## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

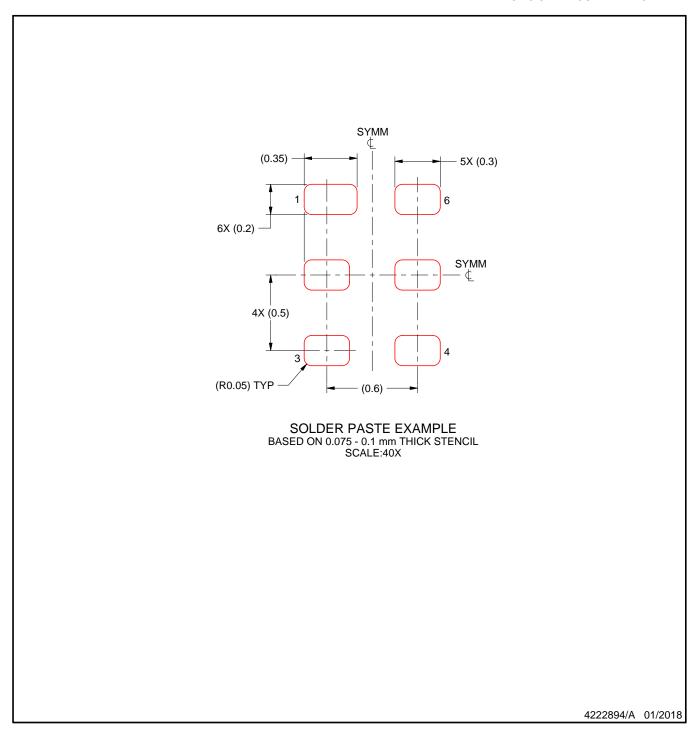




NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



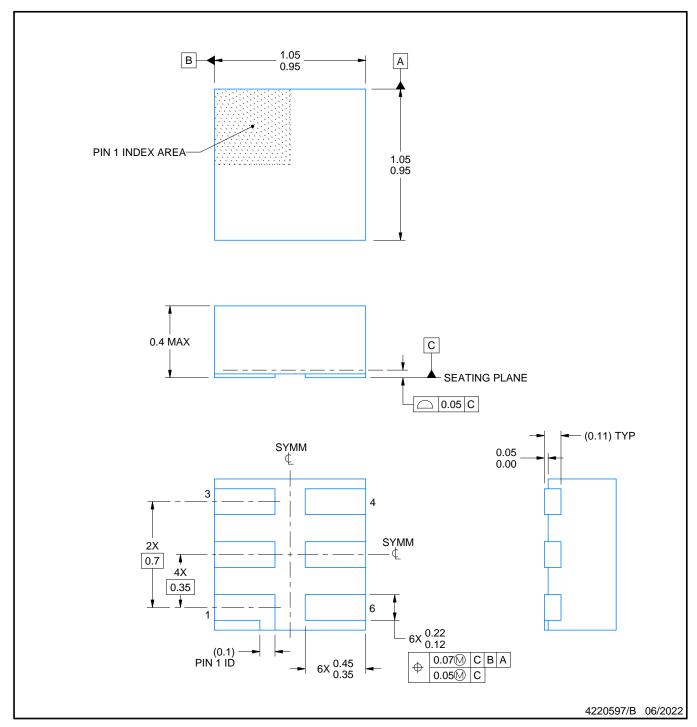


NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







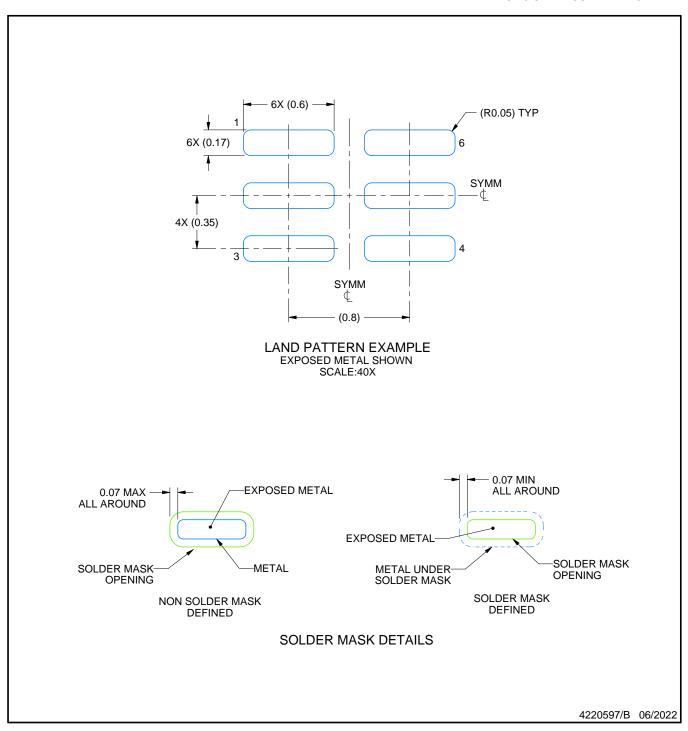
## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC registration MO-287, variation X2AAF.

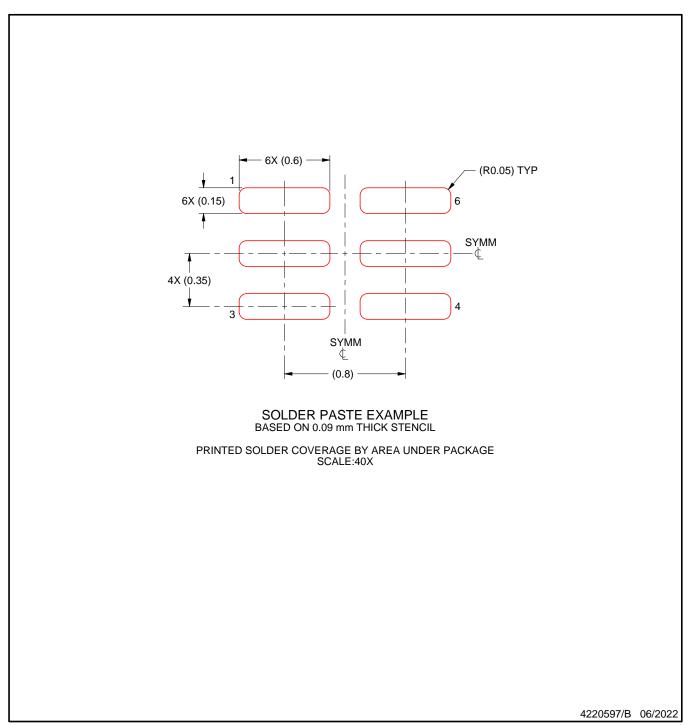




NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).





4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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